AT24C32D

I²C-Compatible (2-Wire) Serial EEPROM 32-Kbit (4,096 x 8)

Features

- Low-Voltage and Standard-Voltage Operation:
  - V_{CC} = 1.7V to 5.5V
- Internally Organized as 4,096 x 8 (32K)
- Industrial Temperature Range: -40°C to +85°C
- I²C-Compatible (2-Wire) Serial Interface:
  - 100 kHz Standard mode, 1.7V to 5.5V
  - 400 kHz Fast mode, 1.7V to 5.5V
  - 1 MHz Fast Mode Plus (FM+), 2.5V to 5.5V
- Schmitt Triggers, Filtered Inputs for Noise Suppression
- Bidirectional Data Transfer Protocol
- Write-Protect Pin for Full Array Hardware Data Protection
- Ultra Low Active Current (3 mA maximum) and Standby Current (6 µA maximum)
- 32-Byte Page Write Mode:
  - Partial page writes allowed
- Random and Sequential Read Modes
- Self-Timed Write Cycle within 5 ms Maximum
- High Reliability:
  - Endurance: 1,000,000 write cycles
  - Data retention: 100 years
- Green Package Options (Lead-free/Halide-free/RoHS compliant)
- Die Sale Options: Wafer Form and Bumped Wafers

Packages

- 8-Lead SOIC, 8-Lead TSSOP, 8-Pad UDFN, 8-Pad XDFN, 5-Lead SOT23 and 8-Ball VFBGA

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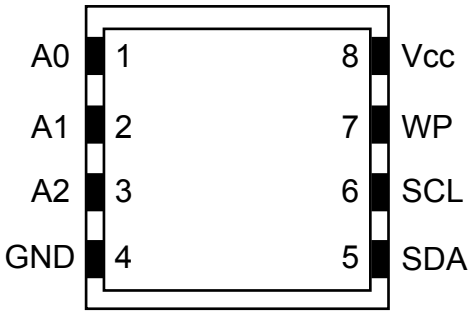
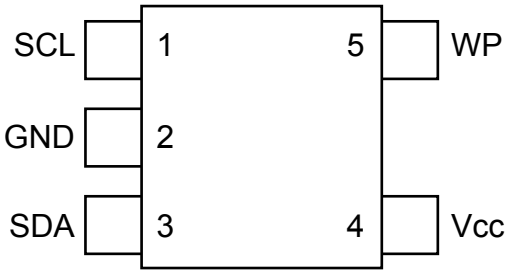
1. Package Types (not to scale)

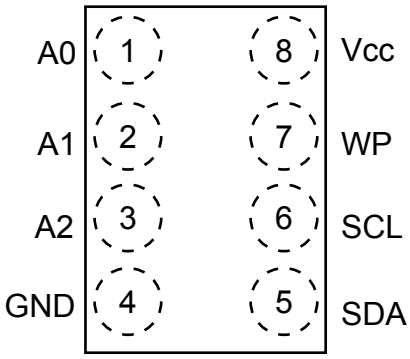
8-pad UDFN/XDFN
(Top View)



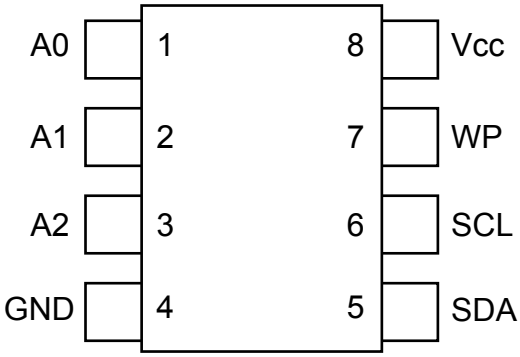
5-lead SOT23[1]
(Top View)



8-ball VFBGA
(Top View)



8-lead SOIC/TSSOP
(Top View)



Note:

1. Refer to 6.1 Device Addressing for details about addressing the SOT23 version of the device.

2. Pin Descriptions

The descriptions of the pins are listed in Table 2-1.

Table 2-1. Pin Function Table

Name	8-Lead SOIC	8-Lead TSSOP	8-Pad UDFN(1)	8-Pad XDFN	5-Lead SOT23	8-Ball VFBGA	Function
A0(2)	1	1	1	1	—	1	Device Address Input
A1(2)	2	2	2	2	—	2	Device Address Input
A2(2)	3	3	3	3	—	3	Device Address Input
GND	4	4	4	4	2	4	Ground
SDA	5	5	5	5	3	5	Serial Data
SCL	6	6	6	6	1	6	Serial Clock
WP(2)	7	7	7	7	5	7	Write-Protect
V_{CC}	8	8	8	8	4	8	Device Power Supply

Note:

1. The exposed pad on this package can be connected to GND or left floating.
2. If the A0, A1, A2 or WP pins are not driven, they are internally pulled down to GND. In order to operate in a wide variety of application environments, the pull-down mechanism is intentionally designed to be somewhat strong. Once these pins are biased above the CMOS input buffer's trip point (~0.5 x V_{CC}), the pull-down mechanism disengages. Microchip recommends connecting these pins to a known state whenever possible.

2.1 Device Address Inputs (A0, A1, A2)

The A0, A1 and A2 pins are device address inputs that are hard-wired (directly to GND or to V_{CC}) for compatibility with other 2-wire Serial EEPROM devices. When the pins are hard-wired, as many as eight devices may be addressed on a single bus system. A device is selected when a corresponding hardware and software match is true. If these pins are left floating, the A0, A1 and A2 pins will be internally pulled down to GND. However, due to capacitive coupling that may appear in customer applications, Microchip recommends always connecting the address pins to a known state. When using a pull-up resistor, Microchip recommends using 10 kΩ or less.

2.2 Ground

The ground reference for the power supply. GND should be connected to the system ground.

2.3 Serial Data (SDA)

The SDA pin is an open-drain bidirectional input/output pin used to serially transfer data to and from the device. The SDA pin must be pulled high using an external pull-up resistor (not to exceed 10 kΩ in value) and may be wire-ORed with any number of other open-drain or open-collector pins from other devices on the same bus.

2.4 Serial Clock (SCL)

The SCL pin is used to provide a clock to the device and to control the flow of data to and from the device. Command and input data present on the SDA pin is always latched in on the rising edge of SCL,

while output data on the SDA pin is clocked out on the falling edge of SCL. The SCL pin must either be forced high when the serial bus is idle or pulled high using an external pull-up resistor.

2.5 Write-Protect (WP)

The write-protect input, when connected to GND, allows normal write operations. When the WP pin is connected directly to V_{CC}, all write operations to the protected memory are inhibited.

If the pin is left floating, the WP pin will be internally pulled down to GND. However, due to capacitive coupling that may appear in customer applications, Microchip recommends always connecting the WP pin to a known state. When using a pull-up resistor, Microchip recommends using 10 kΩ or less.

Table 2-2. Write-Protect

WP Pin Status	Part of the Array Protected
At V_{CC}	Full Array
At GND	Normal Write Operations

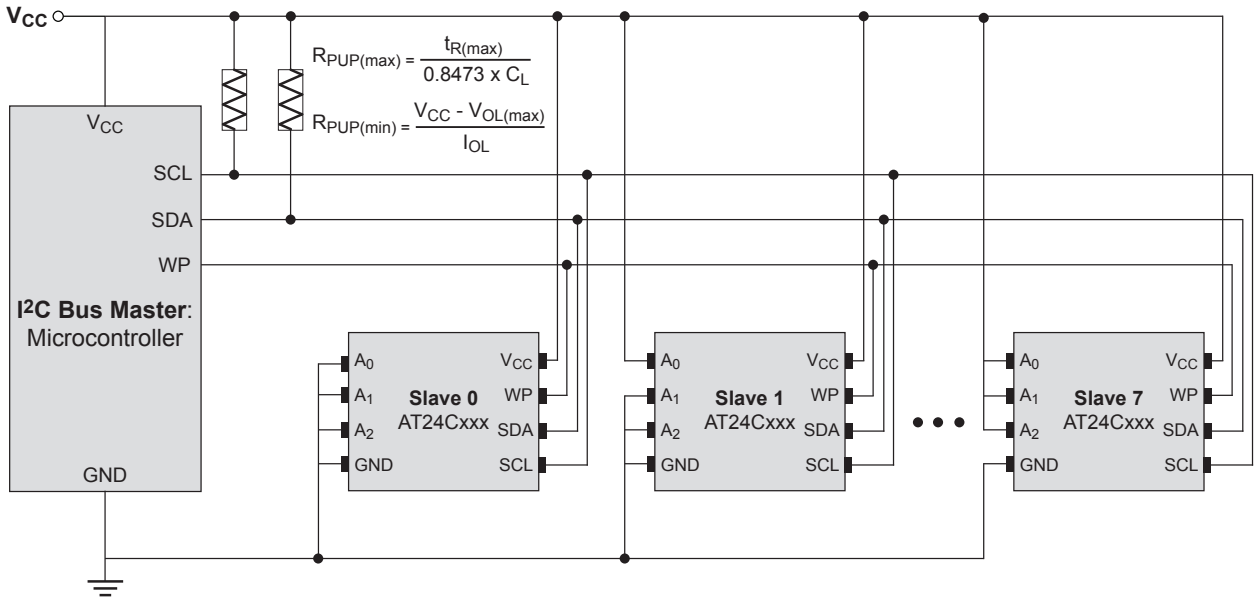
2.6 Device Power Supply

The V_{CC} pin is used to supply the source voltage to the device. Operations at invalid V_{CC} voltages may produce spurious results and should not be attempted.

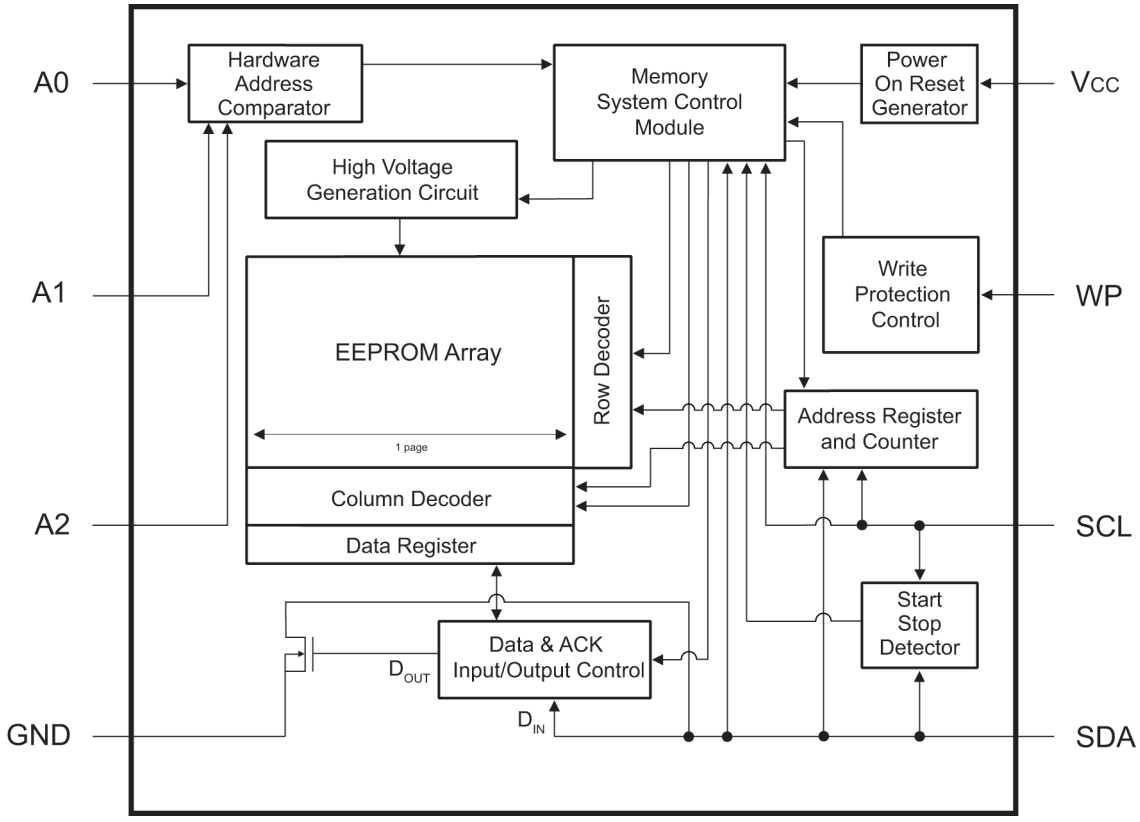
3. Description

The AT24C32D provides 32,768 bits of Serial Electrically Erasable and Programmable Read-Only Memory (EEPROM) organized as 4,096 words of 8 bits each. The device's cascading feature allows up to eight devices to share a common 2-wire bus. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The devices are available in space-saving 8-lead SOIC, 8-lead TSSOP, 8-pad UDFN, 8-pad XDFN, 5-lead SOT23 and 8-ball VFBGA packages. All packages operate from 1.7V to 5.5V.

3.1 System Configuration Using 2-Wire Serial EEPROMs



3.2 Block Diagram



4. Electrical Characteristics

4.1 Absolute Maximum Ratings

Temperature under bias	-55°C to +125°C
Storage temperature	-65°C to +150°C
V_{CC}	6.25V
Voltage on any pin with respect to ground	-1.0V to +7.0V
DC output current	5.0 mA
ESD protection	>3kV

Note: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

4.2 DC and AC Operating Range

Table 4-1. DC and AC Operating Range

AT24C32D		
Operating Temperature (Case)	Industrial Temperature Range	-40°C to +85°C
V_{CC} Power Supply	Low Voltage Grade	1.7V to 5.5V

4.3 DC Characteristics

Table 4-2. DC Characteristics

Parameter	Symbol	Minimum	Typical(1)	Maximum	Units	Test Conditions
Supply Voltage	V_{CC1}	1.7	—	5.5	V	
Supply Current	I_{CC1}	—	0.4	1.0	mA	V_{CC} = 5.0V, Read at 400 kHz
Supply Current	I_{CC2}	—	2.0	3.0	mA	V_{CC} = 5.0V, Write at 400 kHz
Standby Current	I_{SB1}	—	—	1.0	µA	V_{CC} = 1.7V, V_{IN} = V_{CC} or GND
		—	—	6.0	µA	V_{CC} = 5.0V, V_{IN} = V_{CC} or GND
Input Leakage Current	I_{LI}	—	0.10	3.0	µA	V_{IN} = V_{CC} or GND; V_{CC} = 5.0V
Output Leakage Current	I_{LO}	—	0.05	3.0	µA	V_{OUT} = V_{CC} or GND; V_{CC} = 5.0V
Input Low Level	V_{IL}	-0.6	—	V_{CC} x 0.3	V	Note 2
Input High Level	V_{IH}	V_{CC} x 0.7	—	V_{CC} + 0.5	V	Note 2

.....continued						
Parameter	**Symbol**	**Minimum**	**Typical(1)**	**Maximum**	**Units**	**Test Conditions**
Output Low Level	V_{OL1}	—	—	0.2	V	V_{CC} = 1.7V, I_{OL} = 0.15 mA
Output Low Level	V_{OL2}	—	—	0.4	V	V_{CC} = 3.0V, I_{OL} = 2.1 mA

Note:

1. Typical values characterized at T_A = +25°C unless otherwise noted.
2. This parameter is characterized but is not 100% tested in production.

4.4 AC Characteristics

Table 4-3. AC Characteristics(1)

Parameter	Symbol	1.7V		2.5V, 5.0V		Units
		Min.	Max.	Min.	Max.	
Clock Frequency, SCL	f_{SCL}	—	400	—	1000	kHz
Clock Pulse Width Low	t_{LOW}	1300	—	500	—	ns
Clock Pulse Width High	t_{HIGH}	600	—	400	—	ns
Noise Suppression Time(2)	t_I	—	100	—	50	ns
Clock Low to Data Out Valid	t_{AA}	50	900	50	450	ns
Bus Free Time between Stop and Start(2)	t_{BUF}	1300	—	500	—	ns
Start Hold Time	$t_{HD.STA}$	600	—	250	—	ns
Start Set-up Time	$t_{SU.STA}$	600	—	250	—	ns
Data In Hold Time	$t_{HD.DAT}$	0	—	0	—	ns
Data In Set-up Time	$t_{SU.DAT}$	100	—	100	—	ns
Inputs Rise Time(2)	t_R	—	300	—	300	ns
Inputs Fall Time(2)	t_F	—	300	—	100	ns
Stop Set-up Time	$t_{SU.STO}$	600	—	250	—	ns
Data Out Hold Time	t_{DH}	50	—	50	—	ns
Write Cycle Time	t_{WR}	—	5	—	5	ms

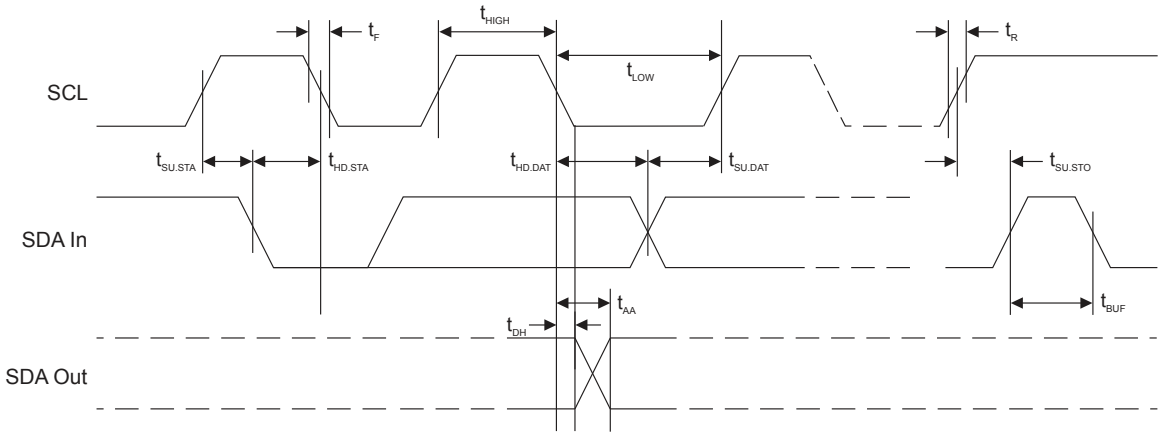
Note:

1. AC measurement conditions:
   - C_L = 100 pF
   - R_{PUP} (SDA bus line pull-up resistor to V_{CC}): 1.3 kΩ (1000 kHz), 4 kΩ (400 kHz), 10 kΩ (100 kHz)
   - Input pulse voltages: 0.3 V_{CC} to 0.7 V_{CC}
   - Input rise and fall times: ≤ 50 ns

– Input and output timing reference voltages: 0.5 x V_{CC}

2. This parameter is ensured by characterization and is not 100% tested.

Figure 4-1. Bus Timing



4.5 Electrical Specifications

4.5.1 Power-up Requirements and Reset Behavior

During a power-up sequence, the V_{CC} supplied to the AT24C32D should monotonically rise from GND to the minimum V_{CC} level, as specified in Table 4-1, with a slew rate no faster than 0.1 V/µs.

4.5.1.1 Device Reset

To prevent inadvertent write operations or any other spurious events from occurring during a power-up sequence, the AT24C32D includes a Power-on Reset (POR) circuit. Upon power-up, the device will not respond to any commands until the V_{CC} level crosses the internal voltage threshold (V_{POR}) that brings the device out of Reset and into Standby mode.

The system designer must ensure the instructions are not sent to the device until the V_{CC} supply has reached a stable value greater than or equal to the minimum V_{CC} level. Additionally, once the V_{CC} is greater than or equal to the minimum V_{CC} level, the bus master must wait at least t_{PUP} before sending the first command to the device. See Table 4-4 for the values associated with these power-up parameters.

Table 4-4. Power-up Conditions(1)

Symbol	Parameter	Min.	Max.	Units
t_{PUP}	Time required after V_{CC} is stable before the device can accept commands	100	—	µs
V_{POR}	Power-on Reset Threshold Voltage	—	1.5	V
t_{POFF}	Minimum time at V_{CC} = 0V between power cycles	500	—	ms

Note:

1. These parameters are characterized but they are not 100% tested in production.

If an event occurs in the system where the V_{CC} level supplied to the AT24C32D drops below the maximum V_{POR} level specified, it is recommended that a full power cycle sequence be performed by first driving the V_{CC} pin to GND, waiting at least the minimum t_{POFF} time and then performing a new power-up sequence in compliance with the requirements defined in this section.

4.5.2 Pin Capacitance

Table 4-5. Pin Capacitance(1)

Symbol	Test Condition	Max.	Units	Conditions
$C_{I/O}$	Input/Output Capacitance (SDA)	8	pF	$V_{I/O}$ = 0V
C_{IN}	Input Capacitance (A0, A1, A2 and SCL)	6	pF	V_{IN} = 0V

Note:

1. This parameter is characterized but is not 100% tested in production.

4.5.3 EEPROM Cell Performance Characteristics

Table 4-6. EEPROM Cell Performance Characteristics

Operation	Test Condition	Min.	Max.	Units
Write Endurance(1)	T_A = 25°C, V_{CC} = 3.3V, Page Write mode	1,000,000	—	Write Cycles
Data Retention(1)	T_A = 55°C	100	—	Years

Note:

1. Performance is determined through characterization and the qualification process.

5. Device Operation and Communication

The AT24C32D operates as a slave device and utilizes a simple I^2C-compatible 2-wire digital serial interface to communicate with a host controller, commonly referred to as the bus master. The master initiates and controls all read and write operations to the slave devices on the serial bus, and both the master and the slave devices can transmit and receive data on the bus.

The serial interface is comprised of just two signal lines: Serial Clock (SCL) and Serial Data (SDA). The SCL pin is used to receive the clock signal from the master, while the bidirectional SDA pin is used to receive command and data information from the master as well as to send data back to the master. Data is always latched into the AT24C32D on the rising edge of SCL and always output from the device on the falling edge of SCL. Both the SCL and SDA pin incorporate integrated spike suppression filters and Schmitt Triggers to minimize the effects of input spikes and bus noise.

All command and data information is transferred with the Most Significant bit (MSb) first. During bus communication, one data bit is transmitted every clock cycle, and after eight bits (one byte) of data have been transferred, the receiving device must respond with either an Acknowledge (ACK) or a No-Acknowledge (NACK) response bit during a ninth clock cycle (ACK/NACK clock cycle) generated by the master. Therefore, nine clock cycles are required for every one byte of data transferred. There are no unused clock cycles during any read or write operation, so there must not be any interruptions or breaks in the data stream during each data byte transfer and ACK or NACK clock cycle.

During data transfers, data on the SDA pin must only change while SCL is low, and the data must remain stable while SCL is high. If data on the SDA pin changes while SCL is high, then either a Start or a Stop condition will occur. Start and Stop conditions are used to initiate and end all serial bus communication between the master and the slave devices. The number of data bytes transferred between a Start and a Stop condition is not limited and is determined by the master. In order for the serial bus to be idle, both the SCL and SDA pins must be in the logic-high state at the same time.

5.1 Clock and Data Transition Requirements

The SDA pin is an open-drain terminal and therefore must be pulled high with an external pull-up resistor. SCL is an input pin that can either be driven high or pulled high using an external pull-up resistor. Data on the SDA pin may change only during SCL low time periods. Data changes during SCL high periods will indicate a Start or Stop condition as defined below. The relationship of the AC timing parameters with respect to SCL and SDA for the AT24C32D are shown in the timing waveform in Figure 4-1. The AC timing characteristics and specifications are outlined in 4.4 AC Characteristics.

5.2 Start and Stop Conditions

5.2.1 Start Condition

A Start condition occurs when there is a high-to-low transition on the SDA pin while the SCL pin is at a stable logic '1' state and will bring the device out of Standby mode. The master uses a Start condition to initiate any data transfer sequence; therefore, every command must begin with a Start condition. The device will continuously monitor the SDA and SCL pins for a Start condition but will not respond unless one is detected. Refer to Figure 5-1 for more details.

5.2.2 Stop Condition

A Stop condition occurs when there is a low-to-high transition on the SDA pin while the SCL pin is stable in the logic '1' state.

The master can use the Stop condition to end a data transfer sequence with the AT24C32D, which will subsequently return to Standby mode. The master can also utilize a repeated Start condition instead of a Stop condition to end the current data transfer if the master will perform another operation. Refer to Figure 5-1 for more details.

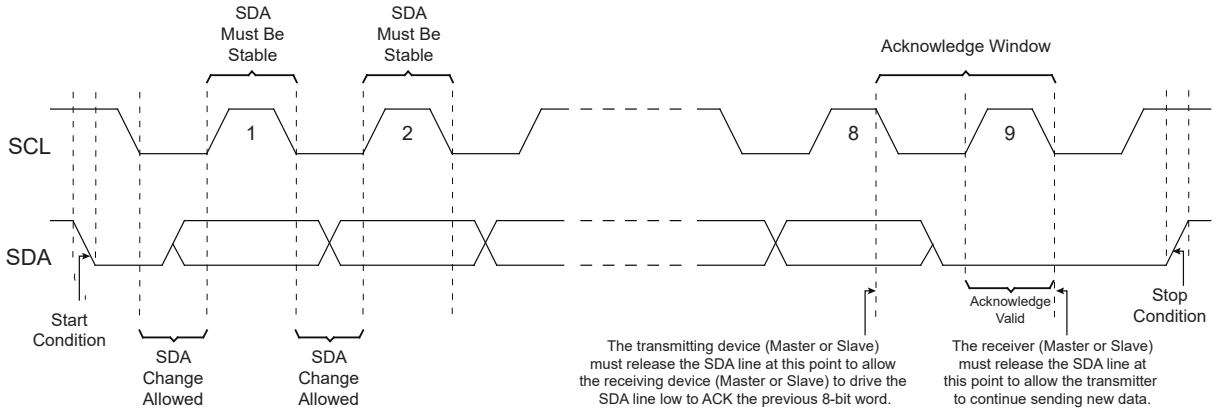
5.3 Acknowledge and No-Acknowledge

After every byte of data is received, the receiving device must confirm to the transmitting device that it has successfully received the data byte by responding with what is known as an Acknowledge (ACK). An ACK is accomplished by the transmitting device first releasing the SDA line at the falling edge of the eighth clock cycle followed by the receiving device responding with a logic '0' during the entire high period of the ninth clock cycle.

When the AT24C32D is transmitting data to the master, the master can indicate that it is done receiving data and wants to end the operation by sending a logic '1' response to the AT24C32D instead of an ACK response during the ninth clock cycle. This is known as a No-Acknowledge (NACK) and is accomplished by the master sending a logic '1' during the ninth clock cycle, at which point the AT24C32D will release the SDA line so the master can then generate a Stop condition.

The transmitting device, which can be the bus master or the Serial EEPROM, must release the SDA line at the falling edge of the eighth clock cycle to allow the receiving device to drive the SDA line to a logic '0' to ACK the previous 8-bit word. The receiving device must release the SDA line at the end of the ninth clock cycle to allow the transmitter to continue sending new data. A timing diagram has been provided in Figure 5-1 to better illustrate these requirements.

Figure 5-1. Start Condition, Data Transitions, Stop Condition and Acknowledge



5.4 Standby Mode

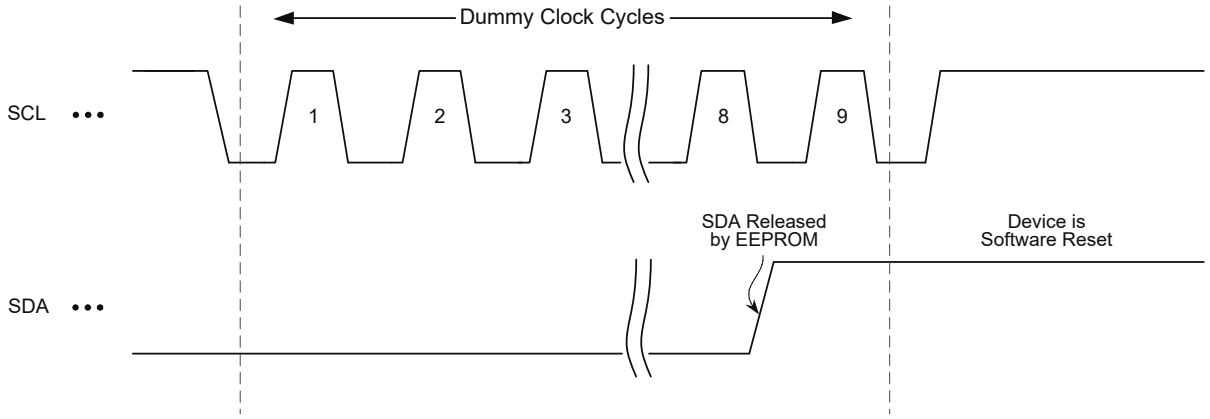
The AT24C32D features a low-power Standby mode that is enabled when any one of the following occurs:

- A valid power-up sequence is performed (see 4.5.1 Power-up Requirements and Reset Behavior).
- A Stop condition is received by the device unless it initiates an internal write cycle (see 7. Write Operations).
- At the completion of an internal write cycle (see 7. Write Operations).

5.5 Software Reset

After an interruption in protocol, power loss or system Reset, any 2-wire device can be protocol reset by clocking SCL until SDA is released by the EEPROM and goes high. The number of clock cycles until SDA is released by the EEPROM will vary. The software Reset sequence should not take more than nine dummy clock cycles. Once the software Reset sequence is complete, new protocol can be sent to the device by sending a Start condition followed by the protocol. Refer to Figure 5-2 for an illustration.

Figure 5-2. Software Reset



In the event that the device is still non-responsive or remains active on the SDA bus, a power cycle must be used to reset the device (see 4.5.1 Power-up Requirements and Reset Behavior).

6. Memory Organization

The AT24C32D is internally organized as 128 pages of 32 bytes each.

6.1 Device Addressing

Accessing the device requires an 8-bit device address byte following a Start condition to enable the device for a read or write operation. Since multiple slave devices can reside on the serial bus, each slave device must have its own unique address so the master can access each device independently.

The Most Significant four bits of the device address byte is referred to as the device type identifier. The device type identifier '1010' (Ah) is required in bits 7 through 4 of the device address byte (see Table 6-1).

Following the 4-bit device type identifier are the hardware slave address bits, A2, A1 and A0. These bits can be used to expand the address space by allowing up to eight Serial EEPROM devices on the same bus. These hardware slave address bits must correlate with the voltage level on the corresponding hardwired device address input pins A0, A1 and A2. The A0, A1 and A2 pins use an internal proprietary circuit that automatically biases the pin to a logic '0' state if the pin is allowed to float. In order to operate in a wide variety of application environments, the pull-down mechanism is intentionally designed to be somewhat strong. Once the pin is biased above the CMOS input buffer's trip point (~0.5 x V_{CC}), the pull-down mechanism disengages. Microchip recommends connecting the A0, A1 and A2 pins to a known state whenever possible.

When utilizing the SOT23 package, the A2, A1 and A0 pins are not accessible and are left floating. The previously mentioned automatic pull-down circuit will set this pin to a logic '0' state. As a result, to properly communicate with the device in the SOT23 package, the A2, A1 and A0 software bits must always be set to logic '0' for any operation. Refer to Table 6-1 to review these bit positions.

The eighth bit (bit 0) of the device address byte is the Read/Write Select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

Upon the successful comparison of the device address byte, the AT24C32D will return an ACK. If a valid comparison is not made, the device will NACK.

Table 6-1. Device Addressing

Package	Device Type Identifier				Hardware Slave Address Bits			R/$\overline{W}$ Select
	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
SOIC, TSSOP, UDFN, XDFN, VFBGA	1	0	1	0	A2	A1	A0	R/$\overline{W}$
SOT23	1	0	1	0	0	0	0	R/$\overline{W}$

For all operations except the current address read, two 8-bit word address bytes must be transmitted to the device immediately following the device address byte. The word address bytes consist of the 12-bit memory array word address, and are used to specify which byte location in the EEPROM to start reading or writing.

The first word address byte contains the four Most Significant bits of the word address (A11 through A8) in bit positions three through zero, as seen in Table 6-2. Bit 7 through bit 4 of the first word address are

“don't care” bits as they are outside of the addressable 32-Kbit range. Upon completion of the first word address byte, the AT24C32D will return an ACK.

Table 6-2. First Word Address Byte

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
X	X	X	X	A11	A10	A9	A8

Next, the second word address byte is sent to the device which provides the remaining eight bits of the word address (A7 through A0). Upon completion of the second word address byte, the AT24C32D will return an ACK. See Table 6-3 to review these bit positions.

Table 6-3. Second Word Address Byte

Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
A7	A6	A5	A4	A3	A2	A1	A0

7. Write Operations

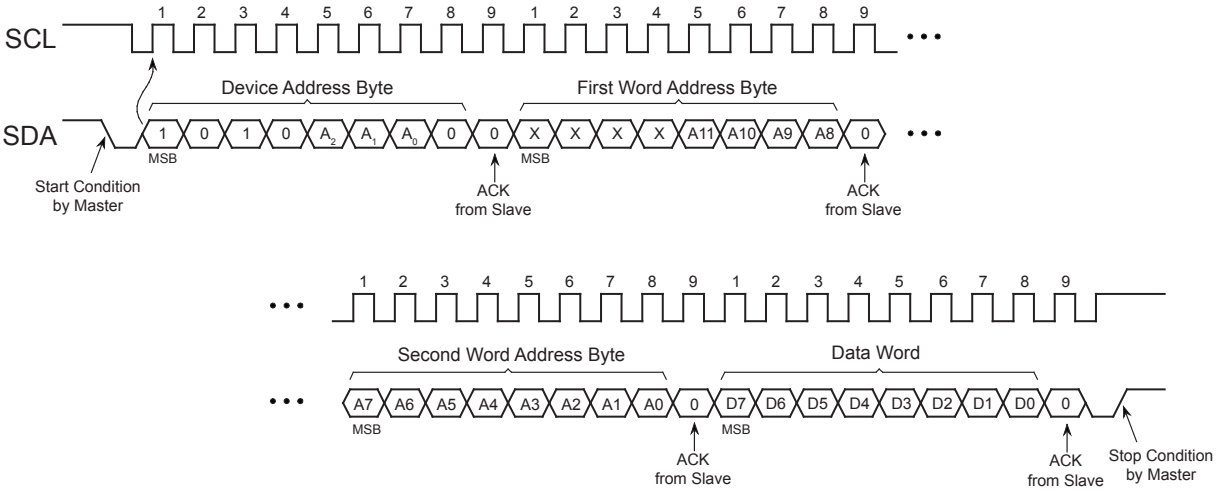
All write operations for the AT24C32D begin with the master sending a Start condition, followed by a device address byte with the R/$\overline{W}$ bit set to logic '0', and then by the word address bytes. The data value(s) to be written to the device immediately follow the word address bytes.

7.1 Byte Write

The AT24C32D supports the writing of a single 8-bit byte. Selecting a data word in the AT24C32D requires a 12-bit word address.

Upon receipt of the proper device address and the word address bytes, the EEPROM will send an Acknowledge. The device will then be ready to receive the 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will respond with an ACK. The addressing device, such as a bus master, must then terminate the write operation with a Stop condition. At that time, the EEPROM will enter an internally self-timed write cycle, which will be completed within t_{WR}, while the data word is being programmed into the nonvolatile EEPROM. All inputs are disabled during this write cycle, and the EEPROM will not respond until the write is complete.

Figure 7-1. Byte Write



7.2 Page Write

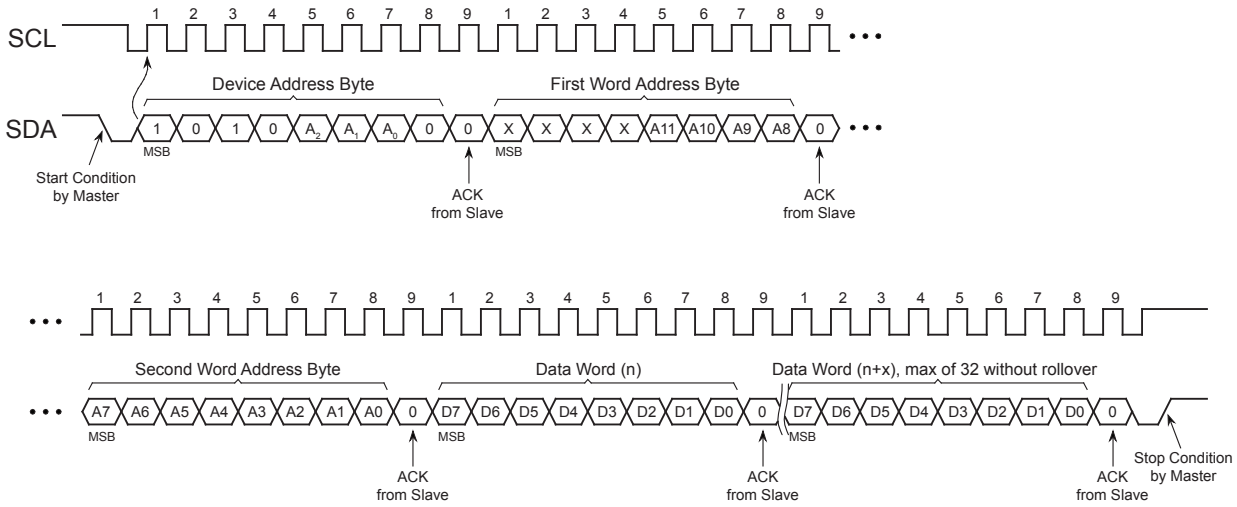
A page write operation allows up to 32 bytes to be written in the same write cycle, provided all bytes are in the same row of the memory array (where address bits A11 throught A5 are the same). Partial page writes of less than 32 bytes are also allowed.

A page write is initiated the same way as a byte write, but the bus master does not send a Stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the bus master can transmit up to thirty one additional data words. The EEPROM will respond with an ACK after each data word is received. Once all data to be written has been sent to the device, the bus master must issue a Stop condition (see Figure 7-2) at which time the internally self-timed write cycle will begin.

The lower five bits of the word address are internally incremented following the receipt of each data word. The higher order address bits are not incremented and retain the memory page row location. Page write

operations are limited to writing bytes within a single physical page, regardless of the number of bytes actually being written. When the incremented word address reaches the page boundary, the address counter will roll-over to the beginning of the same page. Nevertheless, creating a roll-over event should be avoided as previously loaded data in the page could become unintentionally altered.

Figure 7-2. Page Write

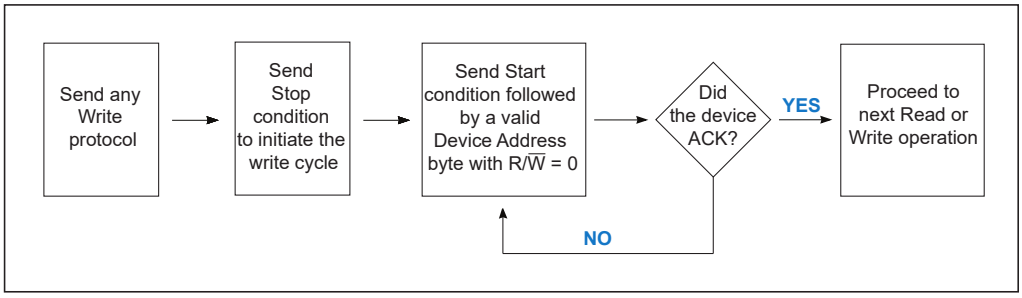


7.3 Acknowledge Polling

An Acknowledge Polling routine can be implemented to optimize time-sensitive applications that would prefer not to wait the fixed maximum write cycle time ($t_{\overline{WR}}$). This method allows the application to know immediately when the Serial EEPROM write cycle has completed, so a subsequent operation can be started.

Once the internally self-timed write cycle has started, an Acknowledge Polling routine can be initiated. This involves repeatedly sending a Start condition followed by a valid device address byte with the R/$\overline{W}$ bit set at logic '0'. The device will not respond with an ACK while the write cycle is ongoing. Once the internal write cycle has completed, the EEPROM will respond with an ACK, allowing a new read or write operation to be immediately initiated. A flowchart has been included below in Figure 7-3 to better illustrate this technique.

Figure 7-3. Acknowledge Polling Flowchart

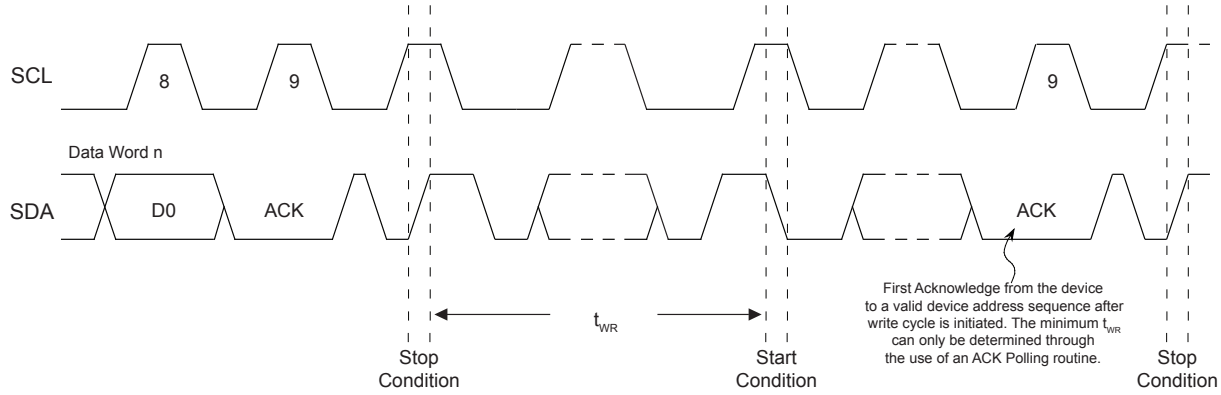


7.4 Write Cycle Timing

The length of the self-timed write cycle (t_{WR}) is defined as the amount of time from the Stop condition that begins the internal write cycle to the Start condition of the first device address byte sent to the AT24C32D

that it subsequently responds to with an ACK. Figure 7-4 has been included to show this measurement. During the internally self-timed write cycle, any attempts to read from or write to the memory array will not be processed.

Figure 7-4. Write Cycle Timing



7.5 Write Protection

The AT24C32D utilizes a hardware data protection scheme that allows the user to write-protect the entire memory contents when the WP pin is at V_{CC} (or a valid V_{IH}). No write protection will be set if the WP pin is at GND or left floating.

Table 7-1. AT24C32D Write-Protect Behavior

WP Pin Voltage	Part of the Array Protected
V_{CC}	Full Array
GND	None – Write Protection Not Enabled

The status of the WP pin is sampled at the Stop condition for every byte write or page write operation prior to the start of an internally self-timed write cycle. Changing the WP pin state after the Stop condition has been sent will not alter or interrupt the execution of the write cycle.

If an attempt is made to write to the device while the WP pin has been asserted, the device will acknowledge the device address, word address and data bytes, but no write cycle will occur when the Stop condition is issued. The device will immediately be ready to accept a new read or write command.

8. Read Operations

Read operations are initiated the same way as write operations with the exception that the Read/Write Select bit in the device address byte must be a logic '1'. There are three read operations:

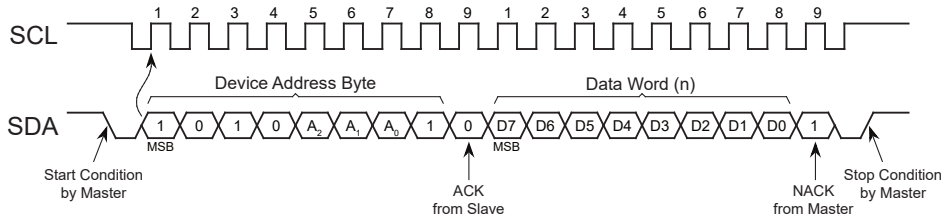
- Current Address Read
- Random Address Read
- Sequential Read

8.1 Current Address Read

The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long the V_{CC} is maintained to the part. The address roll-over during a read is from the last byte of the last page to the first byte of the first page of the memory.

A current address read operation will output data according to the location of the internal data word address counter. This is initiated with a Start condition, followed by a valid device address byte with the R/$\overline{W}$ bit set to logic '1'. The device will ACK this sequence and the current address data word is serially clocked out on the SDA line. All types of read operations will be terminated if the bus master does not respond with an ACK (it NACKs) during the ninth clock cycle. After the NACK response, the master may send a Stop condition to complete the protocol, or it can send a Start condition to begin the next sequence.

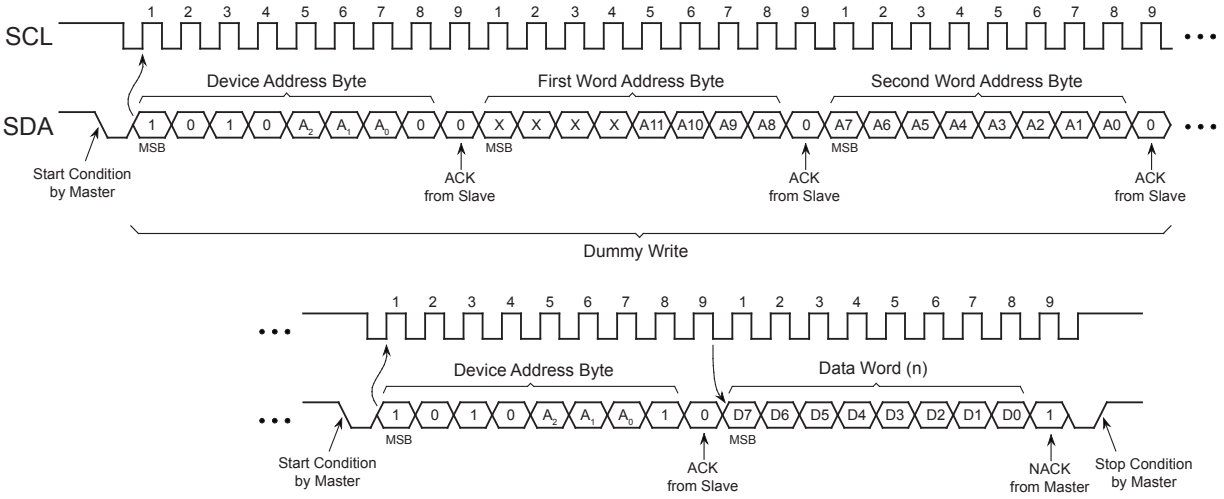
Figure 8-1. Current Address Read



8.2 Random Read

A random read begins in the same way as a byte write operation does to load in a new data word address. This is known as a "dummy write" sequence; however, the data byte and the Stop condition of the byte write must be omitted to prevent the part from entering an internal write cycle. Once the device address and word address are clocked in and acknowledged by the EEPROM, the bus master must generate another Start condition. The bus master now initiates a current address read by sending a Start condition, followed by a valid device address byte with the R/$\overline{W}$ bit set to logic '1'. The EEPROM will ACK the device address and serially clock out the data word on the SDA line. All types of read operations will be terminated if the bus master does not respond with an ACK (it NACKs) during the ninth clock cycle. After the NACK response, the master may send a Stop condition to complete the protocol, or it can send a Start condition to begin the next sequence.

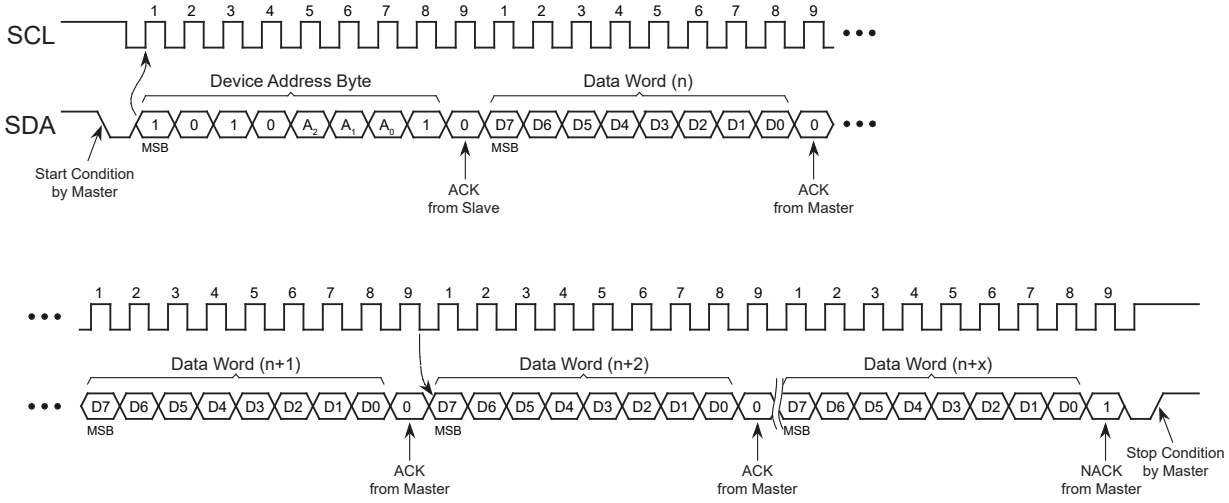
Figure 8-2. Random Read



8.3 Sequential Read

Sequential reads are initiated by either a current address read or a random read. After the bus master receives a data word, it responds with an Acknowledge. As long as the EEPROM receives an ACK, it will continue to increment the word address and serially clock out sequential data words. When the maximum memory address is reached, the data word address will roll-over and the sequential read will continue from the beginning of the memory array. All types of read operations will be terminated if the bus master does not respond with an ACK (it NACKs) during the ninth clock cycle. After the NACK response, the master may send a Stop condition to complete the protocol, or it can send a Start condition to begin the next sequence.

Figure 8-3. Sequential Read



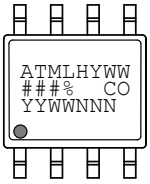
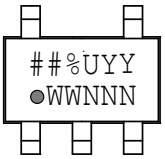
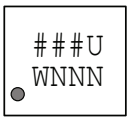
9. Device Default Condition from Microchip

The AT24C32D is delivered with the EEPROM array set to logic '1', resulting in FFh data in all locations.

10. Packaging Information

10.1 Package Marking Information

AT24C32D: Package Marking Information

8-lead SOIC	8-lead TSSOP	8-pad UDFN
		2.0 x 3.0 mm Body
8-pad XDFN	**5-lead SOT23**	**8-ball VFBGA**
1.8 x 2.2 mm Body 		1.5 x 2.0 mm Body 

Note 1: ● designates pin 1

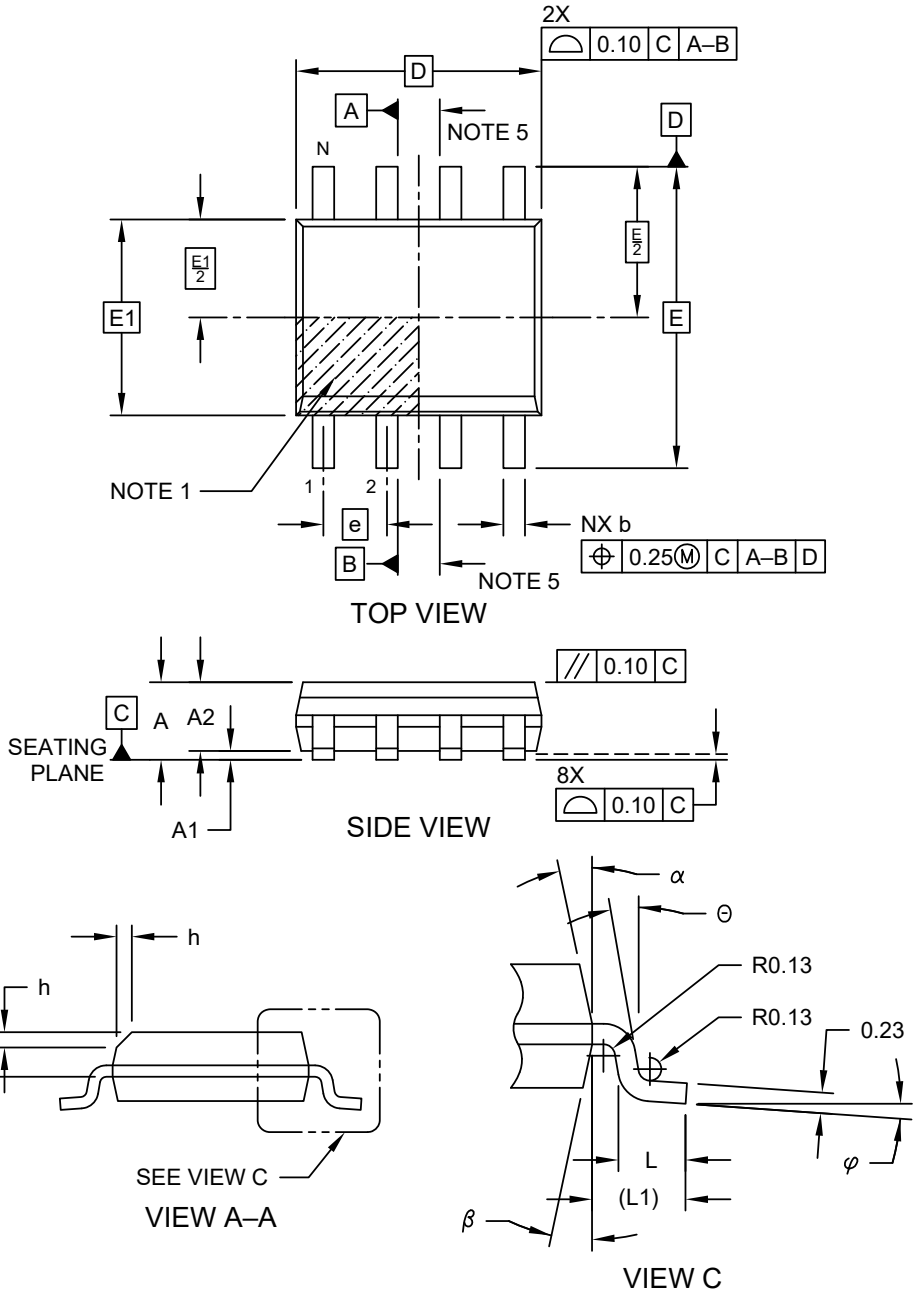
Note 2: Package drawings are not to scale

Note 3: For SOT23 package with date codes before 7B, the bottom line (YMXX) is marked on the bottom side and there is no Country of Assembly (@) mark on the top line.

Catalog Number Truncation					
AT24C32D			Truncation Code ###: 32D / ##: BD		
Date Codes					**Voltages**
YY = Year		Y = Year		WW = Work Week of Assembly	% = Minimum Voltage
16: 2016	20: 2020	6: 2016	0: 2020	02: Week 2	M: 1.7V min
17: 2017	21: 2021	7: 2017	1: 2021	04: Week 4	
18: 2018	22: 2022	8: 2018	2: 2022	...	
19: 2019	23: 2023	9: 2019	3: 2023	52: Week 52	
Country of Origin		**Device Grade**			**Atmel Truncation**
CO = Country of Origin		H or U: Industrial Grade			AT: Atmel ATM: Atmel ATML: Atmel
Trace Code					
NNN = Alphanumeric Trace Code (2 Characters for Small Packages)					

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

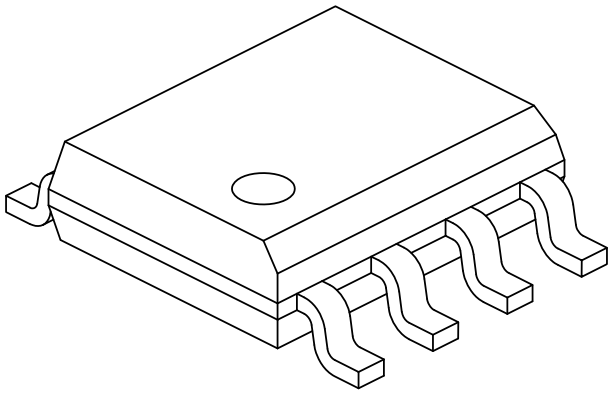
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057-SN Rev D Sheet 1 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		1.27 BSC	
Overall Height	A	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E		6.00 BSC	
Molded Package Width	E1		3.90 BSC	
Overall Length	D		4.90 BSC	
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1		1.04 REF	
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.17	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

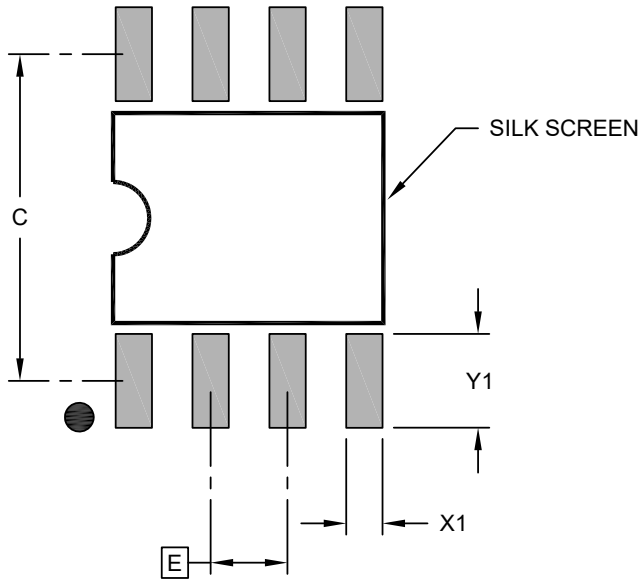
Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
4. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
   REF: Reference Dimension, usually without tolerance, for information purposes only.
5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev D Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	1.27 BSC		
Contact Pad Spacing	C		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

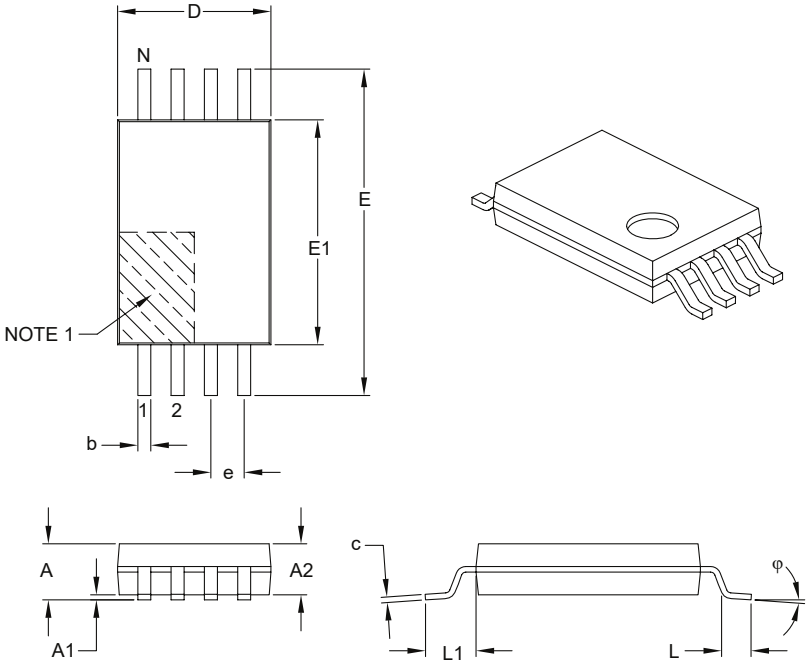
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev B

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		0.65 BSC	
Overall Height	A	–	–	1.20
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	–	0.15
Overall Width	E		6.40 BSC	
Molded Package Width	E1	4.30	4.40	4.50
Molded Package Length	D	2.90	3.00	3.10
Foot Length	L	0.45	0.60	0.75
Footprint	L1		1.00 REF	
Foot Angle	φ	0°	–	8°
Lead Thickness	c	0.09	–	0.20
Lead Width	b	0.19	–	0.30

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
3. Dimensioning and tolerancing per ASME Y14.5M.

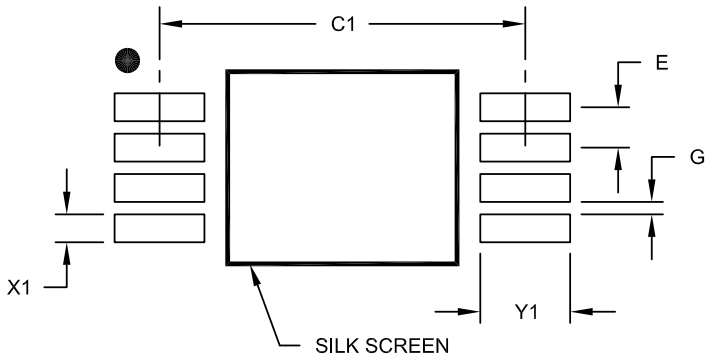
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

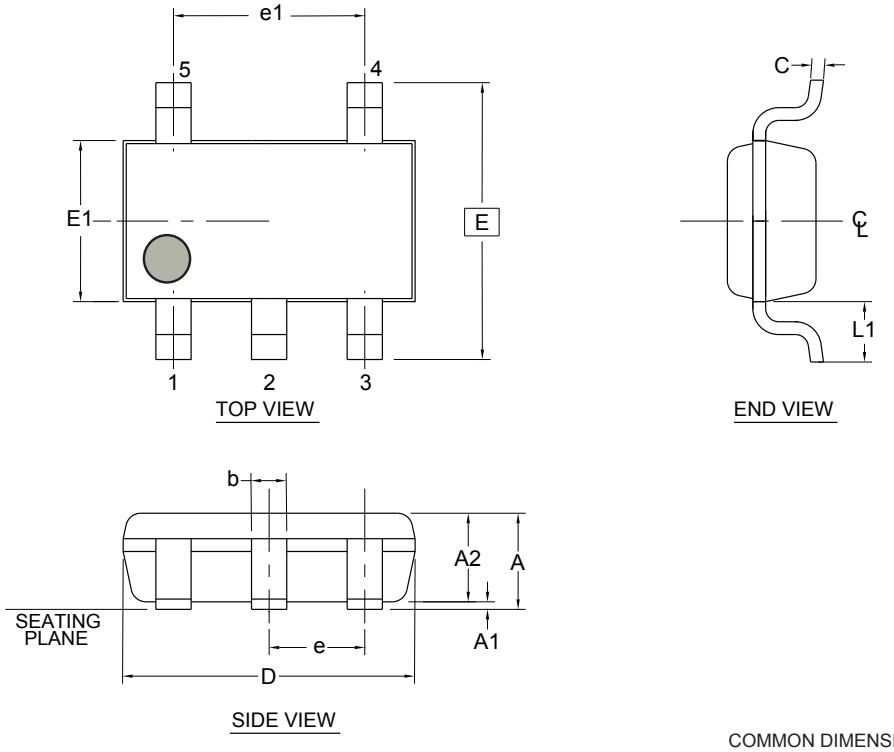
Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E	0.65 BSC		
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2086A



1. Dimension D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.15 mm per side.
2. The package top may be smaller than the package bottom. Dimensions D and E1 are determined at the outermost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.
3. These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.
4. Dimension "b" does not include dambar protrusion. Allowable dambar protrusion shall be 0.08 mm total in excess of the "b" dimension at maximum material condition. The dambar cannot be located on the lower radius of the foot. Minimum space between protrusion and an adjacent lead shall not be less than 0.07 mm.

This drawing is for general information only. Refer to JEDEC Drawing MO-193, Variation AB for additional information.

COMMON DIMENSIONS
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
A	—	—	1.00	
A1	0.00	—	0.10	
A2	0.70	0.90	1.00	
c	0.08	—	0.20	3
D		2.90 BSC		1,2
E		2.80 BSC		1,2
E1		1.60 BSC		1,2
L1		0.60 REF		
e		0.95 BSC		
e1		1.90 BSC		
b	0.30	—	0.50	3,4

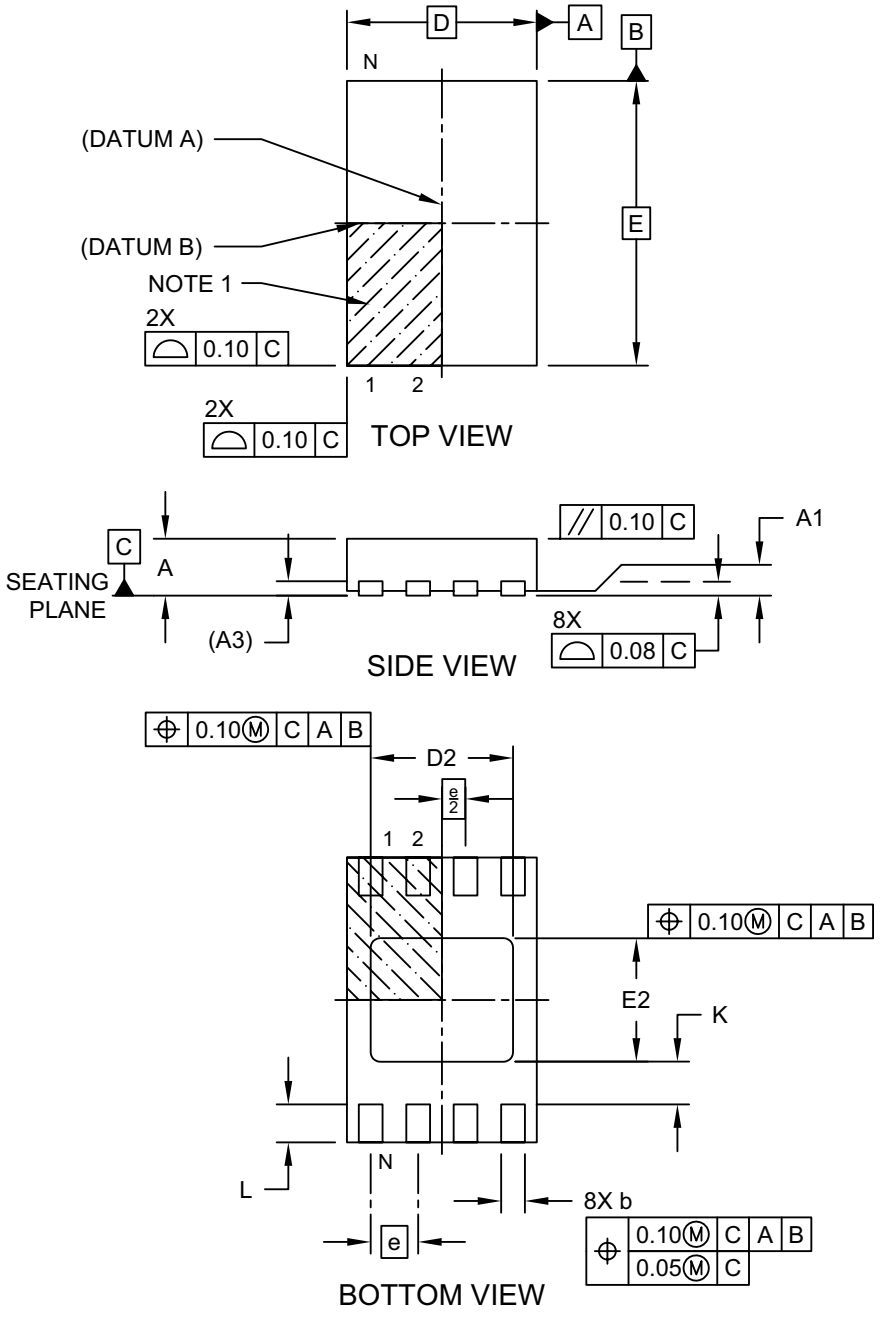
2/2/16

	TITLE	GPC	DRAWING NO.	REV.
	5TS1, 5-lead 1.60mm Body, Plastic Thin Shrink Small Outline Package (Shrink SOT)	TSZ	5TS1	E

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN]
Atmel Legacy YNZ Package

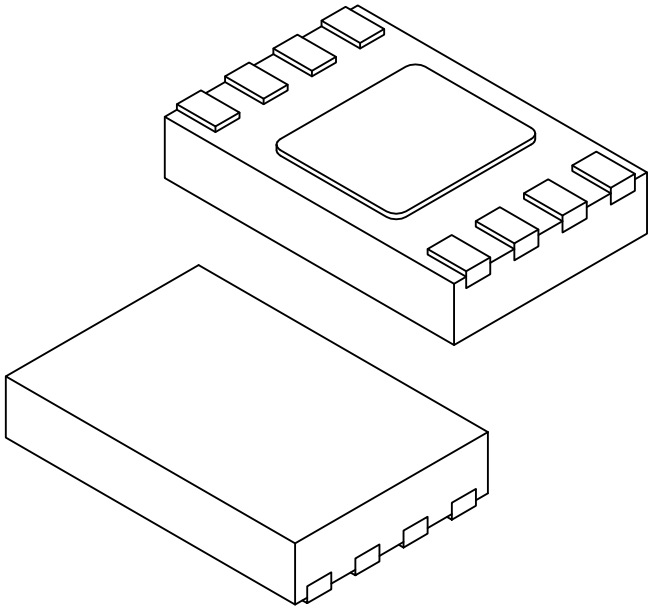
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-21355-Q4B Rev A Sheet 1 of 2

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN]
Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Terminals	N		8	
Pitch	e		0.50 BSC	
Overall Height	A	0.50	0.55	0.60
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3		0.152 REF	
Overall Length	D		2.00 BSC	
Exposed Pad Length	D2	1.40	1.50	1.60
Overall Width	E		3.00 BSC	
Exposed Pad Width	E2	1.20	1.30	1.40
Terminal Width	b	0.18	0.25	0.30
Terminal Length	L	0.35	0.40	0.45
Terminal-to-Exposed-Pad	K	0.20	-	-

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Package is saw singulated
3. Dimensioning and tolerancing per ASME Y14.5M

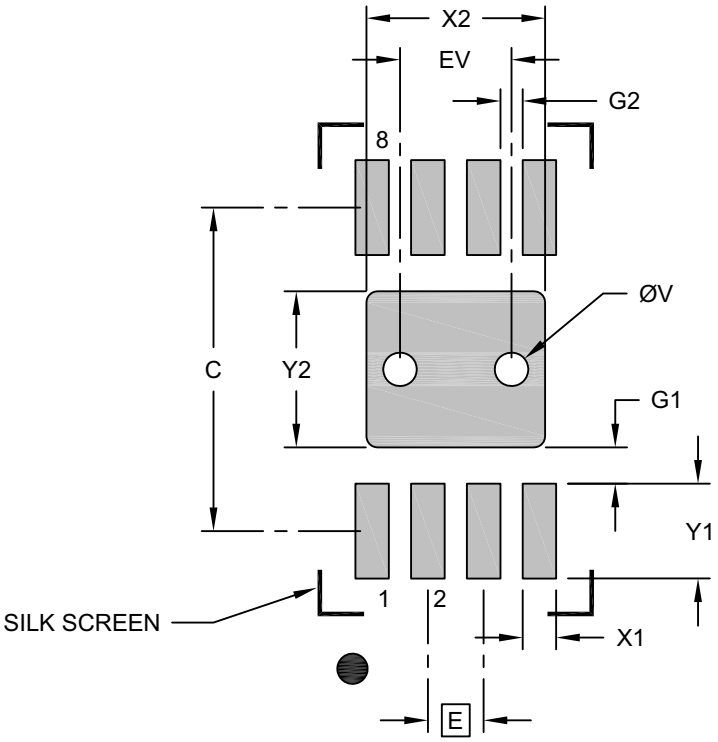
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.

   REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-21355-Q4B Rev A Sheet 2 of 2

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN]
Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



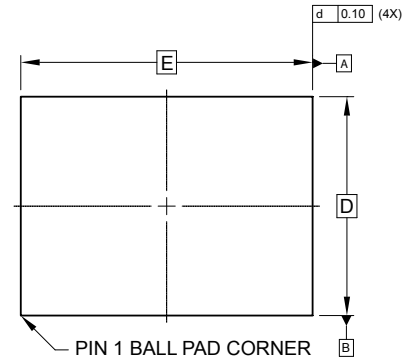
RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.50 BSC	
Optional Center Pad Width	X2			1.60
Optional Center Pad Length	Y2			1.40
Contact Pad Spacing	C		2.90	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.85
Contact Pad to Center Pad (X8)	G1	0.20		
Contact Pad to Contact Pad (X6)	G2	0.33		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

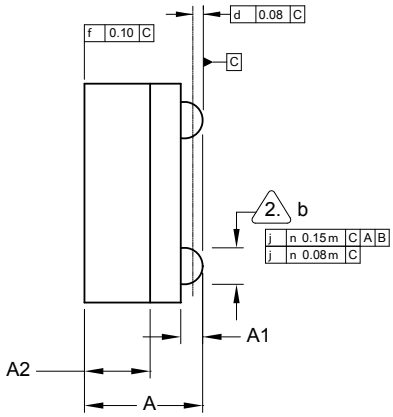
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M
   BSC: Basic Dimension. Theoretically exact value shown without tolerances.
2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

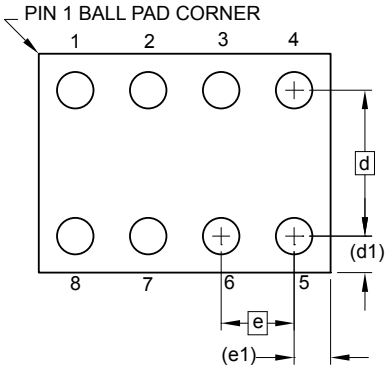
Microchip Technology Drawing C04-21355-Q4B Rev A



TOP VIEW



SIDE VIEW



BOTTOM VIEW
8 SOLDER BALLS

Notes:

1. This drawing is for general information only.
2. Dimension ‘b’ is measured at maximum solder ball diameter.
3. Solder ball composition shall be 95.5Sn-4.0Ag-.5Cu.

COMMON DIMENSIONS
(Unit of Measure - mm)

SYMBOL	MIN	NOM	MAX	NOTE
A	0.73	0.79	0.85	
A1	0.09	0.14	0.19	
A2	0.40	0.45	0.50	
b	0.20	0.25	0.30	2
D	1.50 BSC			
E	2.0 BSC			
e	0.50 BSC			
e1	0.25 REF			
d	1.00 BSC			
d1	0.25 REF			

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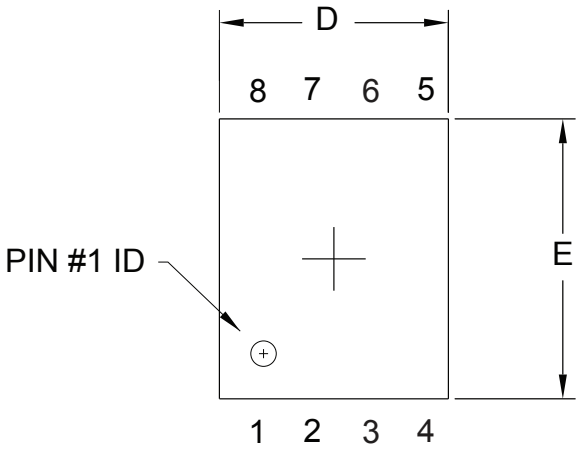
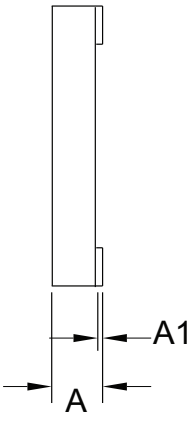
	TITLE	GPC	DRAWING NO.	REV.
	8U3-1, 8-ball, 1.50mm x 2.00mm body, 0.50mm pitch, Very Thin, Fine-Pitch Ball Grid Array Package (VFBGA)	GXU	8U3-1	G

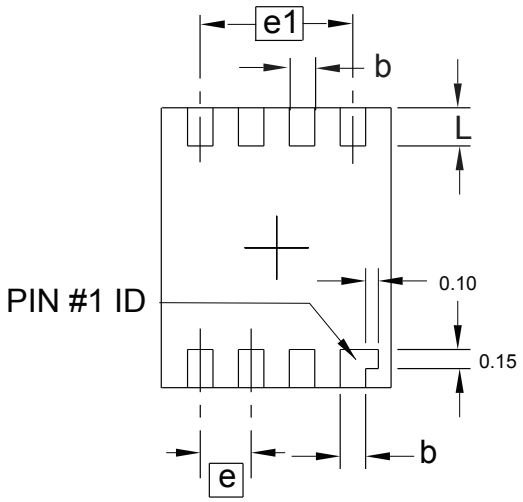
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.



Top View



Side View



End View

COMMON DIMENSIONS
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
A	–	–	0.40	
A1	0.00	–	0.05	
D	1.70	1.80	1.90	
E	2.10	2.20	2.30	
b	0.15	0.20	0.25	
e	0.40 TYP			
e1	1.20 REF			
L	0.26	0.30	0.35	

9/10/2012

	TITLE	GPC	DRAWING NO.	REV.
	8ME1, 8-pad (1.80mm x 2.20mm body) Extra Thin DFN (XDFN)	DTP	8ME1	B

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

11. Revision History

Atmel Document 8866 revision A (August 2013)
Split AT24C32D from AT24C64D due to growing differences in package offerings. Added 5-ball WLCSP package. Updated template and Atmel logos.

Atmel Document 8866 revision B (January 2015)
Added the UDFN Expanded Quantity Option. Updated the 8X and 8MA2 package outline drawings, the part markings page, and the ordering information section

Atmel Document 8866 revision C (December 2015)
Add the AT24C32D-STUMHY-T option and updated the 8S1 and 8MA2 package drawings.

Atmel Document 8866 revision D (December 2016)
Removed AT24C32D-STUMHY-T part number from data sheet.
Removed Product Variation code from Ordering Code Detail.

Part marking SOT23:

- Moved backside mark (YMXX) to front side line2.

- Added @ = Country of Assembly.

Revision A (September 2018)
Updated to the Microchip template. Microchip DS20006047 replaces Atmel document 8866. Corrected t_{LOW} typo from 400 ns to 500 ns. Corrected t_{AA} typo from 550 ns to 450 ns. Updated Part Marking Information. Updated the “Software Reset” section. Added ESD rating. Removed lead finish designation. Updated trace code format in package markings. Updated section content throughout for clarification. Added a figure for “System Configuration Using 2-Wire Serial EEPROMs”. Added POR recommendations section. Removed the 5-ball WLCSP package offering. Replaced the 8U2-1 VFBGA Package Outline Drawing with the 8U3-1 VFBGA Package Outline Drawing. Updated the SOIC, TSSOP and UDFN package drawings to Microchip format.

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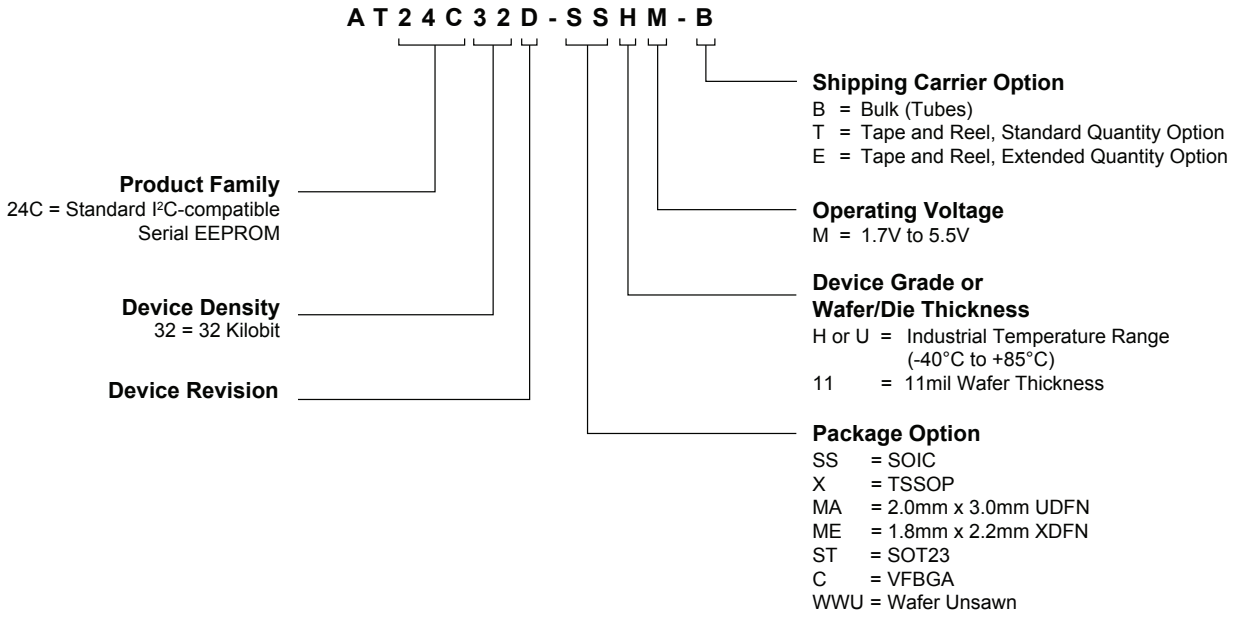

Examples

Device	Package	Package Drawing Code	Package Option	Shipping Carrier Option	Device Grade
AT24C32D-SSHM-B	SOIC	SN	SS	Bulk (Tubes)	Industrial Temperature (-40°C to +85°C)
AT24C32D-SSHM-T	SOIC	SN	SS	Tape and Reel	
AT24C32D-XHM-T	TSSOP	ST	X	Tape and Reel	
AT24C32D-MAHM-T	UDFN	Q4B	MA	Tape and Reel	
AT24C32D-MAHM-E	UDFN	Q4B	MA	Extended Qty. Tape and Reel	
AT24C32D-MEHM-T	XDFN	8ME1	ME	Tape and Reel	
AT24C32D-CUM-T	VFBGA	8U3-1	C	Tape and Reel	
AT24C32D-STUM-T	SOT23	5TS1	ST	Tape and Reel	

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